

T496B106M016BT6110

T496 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 20%, 16 VDC, SMD, MnO2, Molded, Military, Fused, High Reliability, B (0.1%/1000 Hrs), 3.5 Ohms, 2.1 mm, 1411 / 3528

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



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General Information

Series	T496 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Military, Fused, High Reliability
Features	Internal Fuse, High Reliability
RoHS	Yes
Termination	Tin
Typical Component Weight	107.45 mg

Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
T	0.13mm REF
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
B	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
P	0.4mm REF
R	1.5mm REF
X	0.1mm +/-0.1mm REF

Specifications

Capacitance	10 uF
Tolerance	20%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	3500 mOhms (100kHz 25C)
Ripple Current	156 mA (rms, 100kHz 25C)
Leakage Current	1.6 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

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